N-Channel 30-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

Typical Applications:

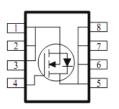
- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY				
V _{DS} (V)	I⊳(A)			
30	22 @ V _{GS} = 10V	11		
30	$30 @ V_{GS} = 4.5V$	9		



FREE





ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)							
Parameter	Symbol	Limit	Units				
Drain-Source Voltage			30	V			
Gate-Source Voltage	V_{GS}	±20	V				
Continuous Drain Current a	T _A =25°C	· I _D	11				
Continuous Drain Current	T _A =70°C	טי	8	Α			
Pulsed Drain Current ^b		I _{DM}	40				
Continuous Source Current (Diode Conduction) a		I _S	4.5	Α			
Power Dissipation ^a	T _A =25°C	P_{D}	3.5	W			
Power Dissipation	T _A =70°C	' D	2	V V			
Operating Junction and Storage Temperature Range		T_J,T_stg	-55 to 150	°C			

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Maximum	Units				
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{\theta JA}$	35	°C/W			
Maximum Junction-to-Ambient	Steady State	IXOJA	81	C/VV			

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Electrical Characteristics

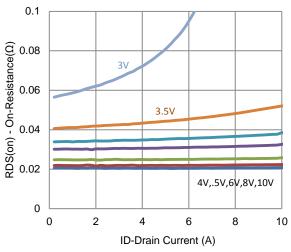
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	ce Threshold Voltage $V_{GS(th)}$ $V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$ 1				V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Brain Gurrent	I _{DSS}	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25		
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			Α	
Drain-Source On-Resistance ^a	r	$V_{GS} = 10 \text{ V}, I_D = 8.2 \text{ A}$			22	mΩ	
Drain-Source On-Resistance	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 6.6 \text{ A}$			30		
Forward Transconductance ^a	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 8.2 \text{ A}$		12		S	
Diode Forward Voltage ^a	V_{SD}	$I_{S} = 2.3 \text{ A}, V_{GS} = 0 \text{ V}$		0.82		V	
		Dynamic ^b					
Total Gate Charge	Q_g	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$		4.1			
Gate-Source Charge	Q_{gs}			1.1		nC	
Gate-Drain Charge	Q_gd	1 _D = 0.2 A		2.0			
Turn-On Delay Time	t _{d(on)}	$V_{DS} = 15 \text{ V}, R_1 = 1.9 \Omega,$		2			
Rise Time	t _r	$V_{DS} = 15 \text{ V}, \text{ K}_{L} - 1.9 \Omega,$ $I_{D} = 8.2 \text{ A},$		4		no	
Turn-Off Delay Time	t _{d(off)}	$V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		16		ns	
Fall Time	t _f	V GEN = 10 V, 1 (GEN = 0.12		4			
Input Capacitance	C _{iss}			360			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ Mhz}$		55		pF	
Reverse Transfer Capacitance	C_{rss}			46			

Notes

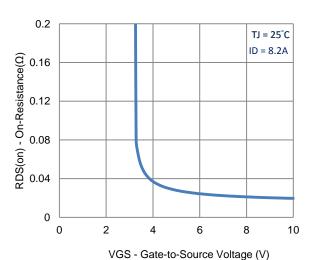
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- Guaranteed by design, not subject to production testing.

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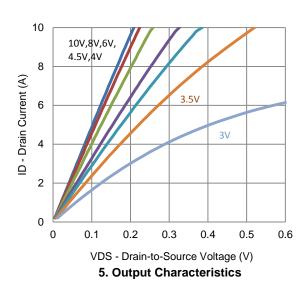
Typical Electrical Characteristics

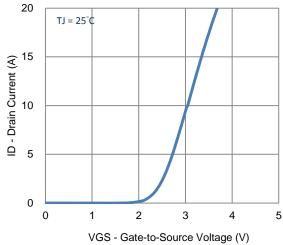


1. On-Resistance vs. Drain Current

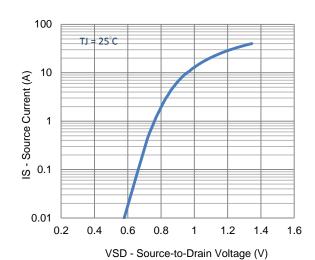


3. On-Resistance vs. Gate-to-Source Voltage

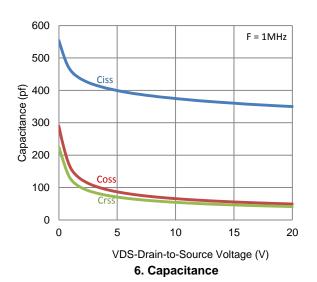




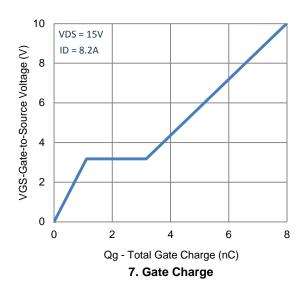
2. Transfer Characteristics

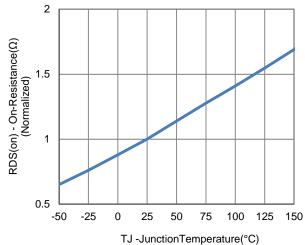


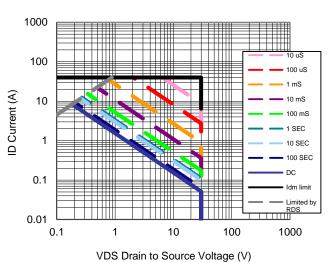
4. Drain-to-Source Forward Voltage



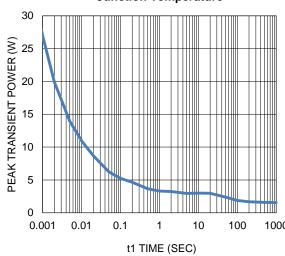
Typical Electrical Characteristics





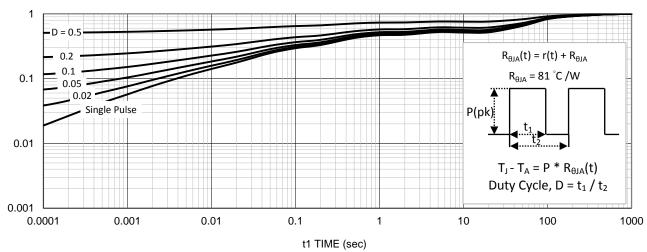






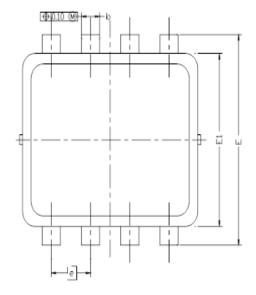
9. Safe Operating Area

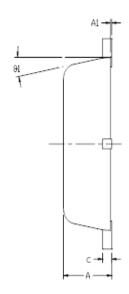
10. Single Pulse Maximum Power Dissipation

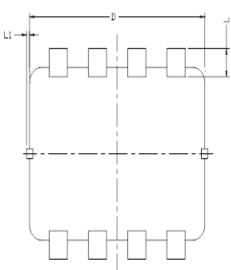


11. Normalized Thermal Transient Junction to Ambient

Package Information







Г	IM.	MILLIMETERS			INCHES			
L)IIV	MIN	NDM	MAX	MIN	NDM	MAX	
	Α	0.700	0,80	0,900	0.0276	0.0315	0.0354	
	A1	0.00		0.05	0,000		0.002	
	b	0.24	0.30	0.35	0.009	0.012	0.014	
	\subset	0.08	0.152	0.25	0.003	0,006	0.010	
	D	2	2.90 BS	С	0.114 BSC			
	E	2.80 BSC 0.110 F					С	
	E1	2	2,30 BS	С	0.091 BSC			
	9	0.65 BSC			0.026 BSC			
	L	0.20	0.375	0.450	0.008	0.0148	0.0177	
	L1	0		0.100	0		0.004	
	01	0	10	12	0	10	12	